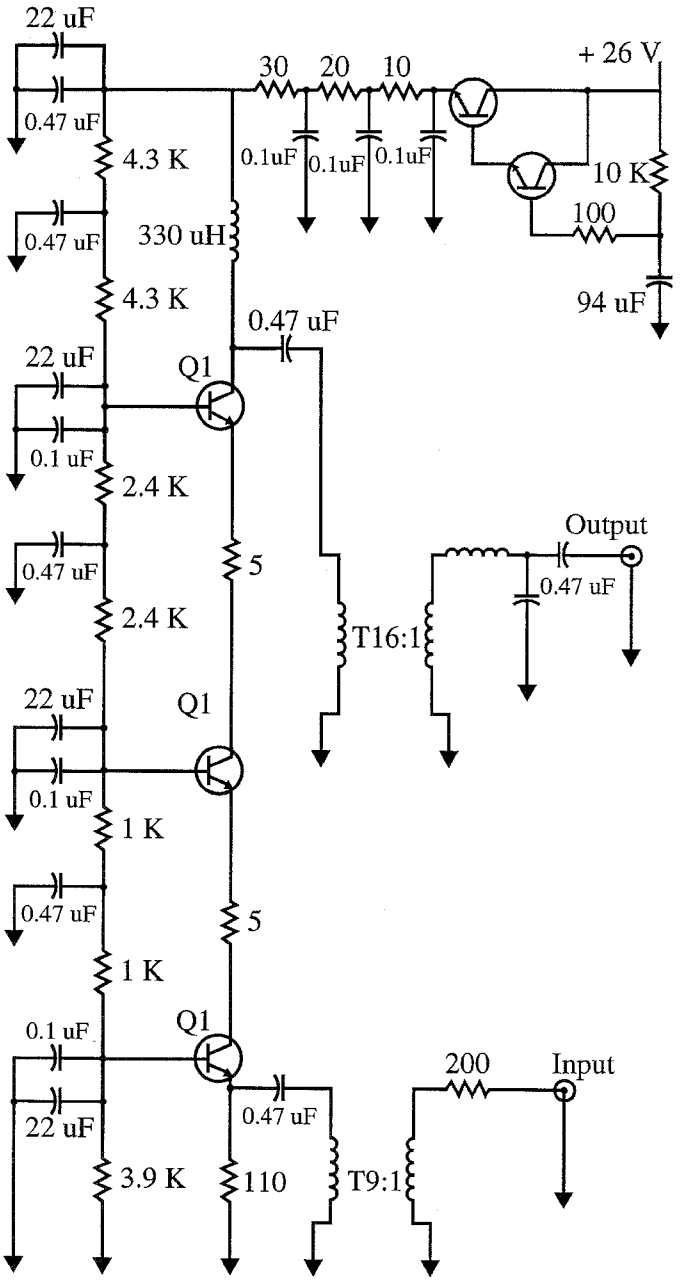

Fig. 12. A 5 MHz isolation amplifier.

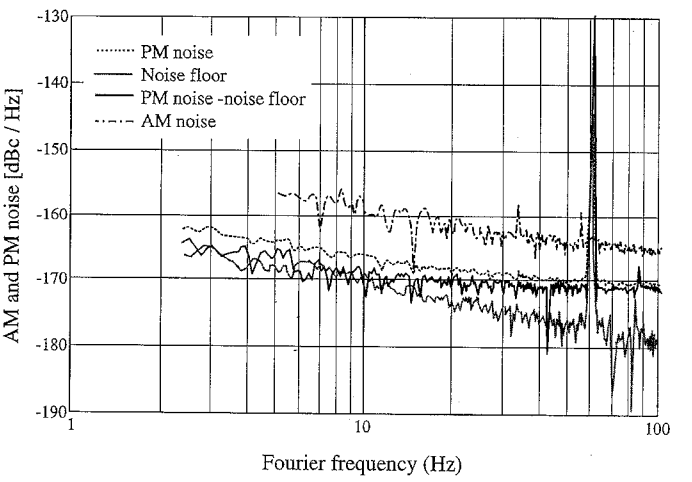

Fig. 13. PM and AM noise for an isolation amplifier at 5 MHz.

gain) with PM noise of $\mathcal{L}(10\text{ Hz}) \leq -162$ dBc/Hz. AM and PM noise in CC and CB configurations was also studied. Due to their small phase shift and small gain, these stages have very low 1/f AM and PM noise. Our 5 MHz CC amplifier had noise levels similar to the noise floor of the measurement systems [$\mathcal{L}(10\text{ Hz}) \leq -169$ dBc/Hz, $1/2S_a(10\text{ Hz}) \leq -162$ dBc/Hz]. In addition, our 5 MHz distribution amplifier (composed of 3 CB stages) had noise levels of $\mathcal{L}(10\text{ Hz}) \leq -168$ dBc/Hz, and $1/2S_a(10\text{ Hz}) \leq -160$ dBc/Hz.

ACKNOWLEDGMENTS

The authors thank S. R. Jefferts, T. E. Parker, F. G. Ascarrunz and M. Sicardi for helpful discussions on the topic.

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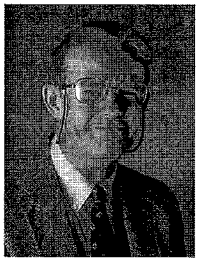

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